TOSHIBA CMOS Didital Integrated Circuit Silicon Monolithic

# TC7MET138AFK

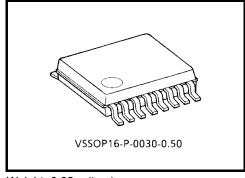
#### 3-to-8 Line Decoder

The TC7MET138AFK is an advanced high speed CMOS 3-to-8 line decoder fabricated with silicon gate  $\rm C^2MOS$  technology. It achieves the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

When the device is enabled, 3 binary select inputs (A, B and C) determine which one of the outputs  $(\overline{Y}0 - \overline{Y}7)$  will go low.

When enable input G1 is held low or either  $\overline{G}2A$  or  $\overline{G}2B$  is held high, decoding function is inhibited and all outputs go high. G1,  $\overline{G}2A$ , and  $\overline{G}2B$  inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

The input voltage are compatible with TTL output voltage. This device may be used as a level converter for interfacing  $3.3\ V$  to  $5\ V$  system.



Weight: 0.02 g (typ.)

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output <sup>(Note)</sup> pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note:  $V_{CC} = 0 V$ 

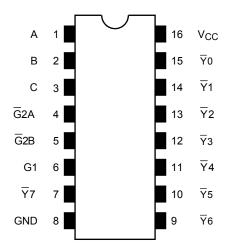
#### **Features**

- High speed:  $t_{pd} = 7.6 \text{ ns (typ.)} (V_{CC} = 5 \text{ V})$
- Low power dissipation:  $I_{CC} = 4 \mu A \text{ (max) (Ta} = 25 ^{\circ}\text{C)}$
- Compatible with TTL outputs:  $V_{IL} = 0.8 \text{ V (max)}$

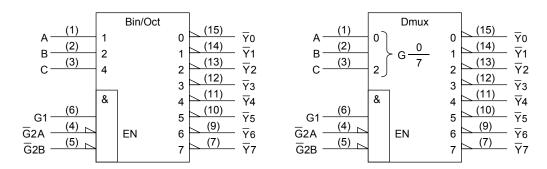
$$V_{IH} = 2.0 \text{ V (min)}$$

- Power down protection is provided on all inputs and outputs.
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Pin and function compatible with the 74 series (74AC/HC/ALS/LS etc.) 138 type.

# Pin Assignment (top view)



# **IEC Logic Symbol**

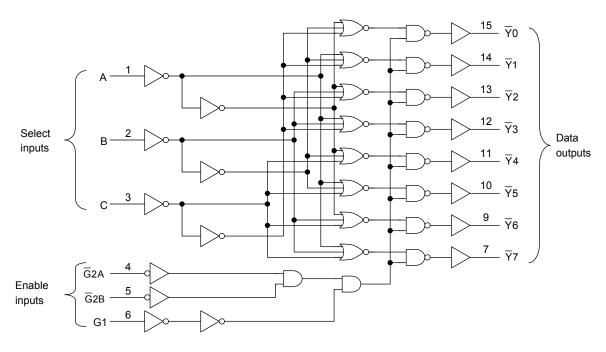


### **Truth Table**

	Inputs					Outputs								
	Enable			Select			<u></u>	<u></u>	_ Y3	<u></u>	_ Y5	<u>7</u> 6	<u>7</u> 7	Selected Output
G1	G2A	G <sub>2</sub> B	С	В	Α	₹0	11	12	13	14	13	10	1 /	
L	Х	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None
Х	Н	Х	Х	X	X	Η	Η	Н	Н	Η	Н	Η	Η	None
Х	Х	Η	Х	X	X	Η	Η	Н	Н	Η	Н	Η	Η	None
Н	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	₹0
Н	L	L	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	₹1
Н	L	L	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н	Y2
Н	L	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н	Н	<del>Y</del> 3
Н	L	L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н	₹4
Н	L	L	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н	Ȳ5
Н	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	₹6
Н	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L	Ÿ7

X: Don't care

#### **System Diagram**



### **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5~7.0	V
DC input voltage	V <sub>IN</sub>	-0.5~7.0	V
DC output voltage	V	−0.5~7.0 (Note 2)	V
DC output voltage	V <sub>OUT</sub>	-0.5~V <sub>CC</sub> + 0.5 (Note 3)	V
Input diode current	I <sub>IK</sub>	-20	mA
Output diode current	lok	±20 (Note 4)	mA
DC output current	lout	±25	mA
DC V <sub>CC</sub> /ground current	Icc	±75	mA
Power dissipation	P <sub>D</sub>	180	mW
Storage temperature	T <sub>stg</sub>	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2:  $V_{CC} = 0 V$ 

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$ 

## **Operating Ranges (Note 1)**

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	4.5~5.5	V	
Input voltage	V <sub>IN</sub>	0~5.5	٧	
Output voltage	V <sub>OUT</sub>	0~5.5 (Note 2)	V	
Output voltage	V001	0~V <sub>CC</sub> (Note 3)	V	
Operating temperature	T <sub>opr</sub>	-40~85	°C	
Input rise and fall time	dt/dv	0~20	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Note 2:  $V_{CC} = 0 V$ 

Note 3: High or low state.

#### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics		Symbol	Test Condition			Ta = 25°C			Ta = -4	Unit	
		Symbol			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
Input voltage	High level	V <sub>IH</sub>	_		4.5~5.5	2.0	_	_	2.0	_	V
input voitage	Low level	V <sub>IL</sub>		_	4.5~5.5		_	0.8	_	0.8	•
	High level	Voн	V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OH</sub> = -50 μA	4.5	4.4	4.5	_	4.4	_	V
Output voltage	riigirievei	VOH		I <sub>OH</sub> = -8 mA	4.5	3.94	_	_	3.80	_	
Output voitage	Low level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub>	$I_{OL} = 50 \mu A$	4.5	_	0	0.1	_	0.1	
				I <sub>OL</sub> = 8 mA	4.5	_	_	0.36	_	0.44	
Input leakage cu	Input leakage current		V <sub>IN</sub> = 5.5 V or GND		0~5.5	_	_	±0.1	_	±1.0	μА
Quiescent supply current		Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	4.0	_	40.0	μΑ
		Ісст	Per input: V <sub>IN</sub> = 3.4 V Other input: V <sub>CC</sub> or GND		5.5		_	1.35	_	1.50	mA
Output leakage	I <sub>OPD</sub>	V <sub>OUT</sub> = 5.	5 V	0			0.5		5.0	μΑ	

## AC Characteristics (Input: $t_r = t_f = 3$ ns)

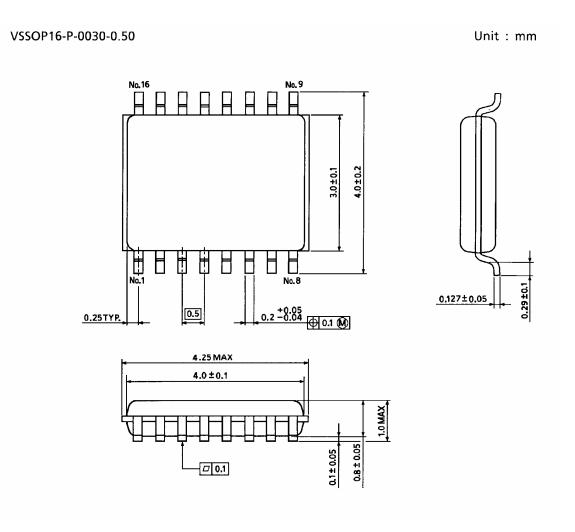
Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -4	Unit	
Characteristics	Symbol	rest Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Min	Max	Offic
Propagation delay time	t <sub>pLH</sub>		5.0 ± 0.5	15	_	7.6	10.4	1.0	12.0	ns
(A, B, C- $\overline{Y}$ )	tpHL		3.0 ± 0.5	50	_	8.1	11.4	1.0	13.0	115
Propagation delay time	t <sub>pLH</sub>	_	5.0 ± 0.5	15	_	6.6	9.1	1.0	10.5	- ns
(G1- \overline{Y})	t <sub>pHL</sub>			50	_	7.1	10.1	1.0	11.5	
Propagation delay time	t <sub>pLH</sub>		5.0 ± 0.5	15	_	7.0	9.6	1.0	11.0	- ns
( <del>G</del> 2 - <del>Y</del> )	tpHL	_		50	_	7.5	10.6	1.0	12.0	
Input capacitance	C <sub>IN</sub>		_		_	4	10	_	10	pF
Power dissipation capacitance	$C_{PD}$			(Note)	_	49	_		_	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC \text{ (opr)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

# **Package Dimensions**



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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